

**DESCRIPTION**

The 82S180 and 82S181 are field programmable, which means that custom patterns are immediately available by following the fusing procedure given in this data sheet. The standard 82S180 and 82S181 are supplied with all outputs at logical low. Outputs are programmed to a logic high level at any specified address by fusing a Ni-Cr link matrix.

These devices include on-chip decoding and 4 chip enable inputs for ease of memory expansion. They feature either open collector or tri-state outputs for optimization of word expansion in bused organizations.

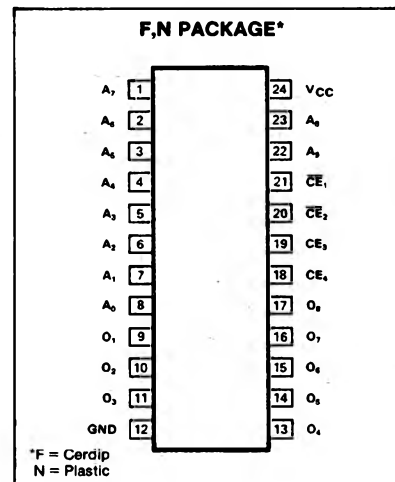
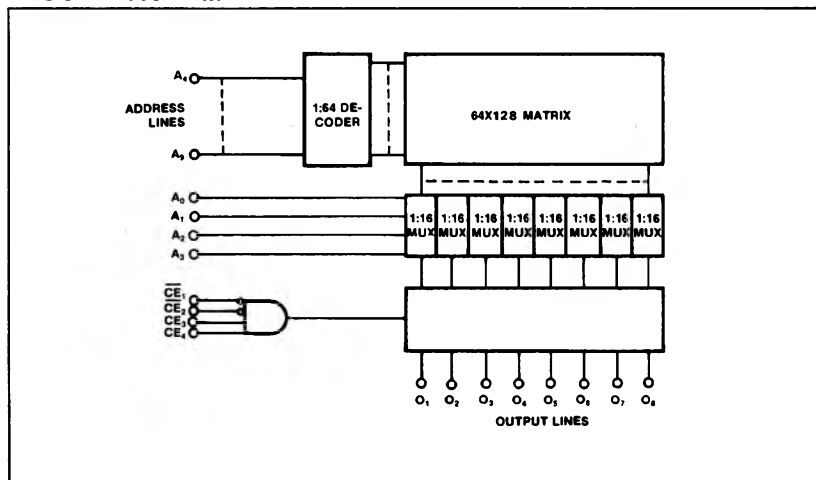
The 82S180 and 82S181 are available in both the commercial and military temperature ranges. For the commercial temperature range (0°C to +75°C) specify N82S180/181, F or N, and for the military temperature range (-55°C to +125°C) specify S82S180/181, F.

**FEATURES**

- **Address access time:**  
N82S180/181: 70ns max  
S82S180/181: 90ns max
- **Power dissipation:** 85μW/bit typ
- **Input loading:**  
N82S180/181: -100μA max  
S82S180/181: -150μA max
- **On-chip address decoding**
- **Output options:**  
82S180: Open collector  
82S181: Tri-state
- **No separate fusing pins**
- **Unprogrammed outputs are low level**
- **Fully TTL compatible**

**APPLICATIONS**

- Prototyping/volume production
- Sequential controllers
- Microprogramming
- Hardwired algorithms
- Control store
- Random logic
- Code conversion

**PIN CONFIGURATION****BLOCK DIAGRAM****ABSOLUTE MAXIMUM RATINGS**

| PARAMETER        |                    | RATING      | UNIT |
|------------------|--------------------|-------------|------|
| V <sub>CC</sub>  | Supply voltage     | +7          | Vdc  |
| V <sub>IN</sub>  | Input voltage      | +5.5        | Vdc  |
| V <sub>OH</sub>  | Output voltage     |             | Vdc  |
| V <sub>O</sub>   | High (82S180)      | +5.5        |      |
|                  | Off-state (82S181) | +5.5        |      |
| T <sub>A</sub>   | Temperature range  |             | °C   |
|                  | Operating          |             |      |
|                  | N82S180/181        | 0 to +75    |      |
|                  | S82S180/181        | -55 to +125 |      |
| T <sub>STG</sub> | Storage            | -65 to +150 |      |

**DC ELECTRICAL CHARACTERISTICS** N82S180/181:  $0^{\circ}\text{C} \leq T_A \leq +75^{\circ}\text{C}$ ,  $4.75\text{V} \leq V_{CC} \leq 5.25\text{V}$   
 S82S180/181:  $-55^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ ,  $4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ 

| PARAMETER                                             | TEST CONDITIONS <sup>1</sup>           | N82S180/181                                                                                                                                                                                                                                                                                                                                                                                               |                  |     | S82S180/181 |                  |     | UNIT |
|-------------------------------------------------------|----------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------|-----|-------------|------------------|-----|------|
|                                                       |                                        | Min                                                                                                                                                                                                                                                                                                                                                                                                       | Typ <sup>2</sup> | Max | Min         | Typ <sup>2</sup> | Max |      |
| V <sub>IL</sub><br>V <sub>IH</sub><br>V <sub>IC</sub> | Input voltage<br>Low<br>High<br>Clamp  | I <sub>IN</sub> = -18mA                                                                                                                                                                                                                                                                                                                                                                                   |                  |     |             |                  |     | V    |
|                                                       |                                        |                                                                                                                                                                                                                                                                                                                                                                                                           |                  |     |             |                  |     |      |
| V <sub>OL</sub><br>V <sub>OH</sub>                    | Output voltage<br>Low<br>High (82S181) | I <sub>OUT</sub> = 9.6mA<br>CE <sub>1</sub> = low, I <sub>OUT</sub> = -2mA, CE <sub>2</sub> = low,<br>CE <sub>2</sub> = high, CE <sub>4</sub> = high, high stored                                                                                                                                                                                                                                         |                  |     |             |                  |     | V    |
|                                                       |                                        |                                                                                                                                                                                                                                                                                                                                                                                                           |                  |     |             |                  |     |      |
| I <sub>IL</sub><br>I <sub>IH</sub>                    | Input current<br>Low<br>High           | V <sub>IN</sub> = 0.45V<br>V <sub>IN</sub> = 5.5V                                                                                                                                                                                                                                                                                                                                                         |                  |     |             |                  |     | μA   |
|                                                       |                                        |                                                                                                                                                                                                                                                                                                                                                                                                           |                  |     |             |                  |     |      |
| I <sub>OLK</sub>                                      | Output current<br>Leakage (82S180)     | CE <sub>1</sub> = high, V <sub>OUT</sub> = 5.5V, CE <sub>2</sub> = high,<br>CE <sub>3</sub> = low, CE <sub>4</sub> = low<br>CE <sub>1</sub> = high, V <sub>OUT</sub> = 0.5V, CE <sub>2</sub> = high,<br>CE <sub>3</sub> = low, CE <sub>4</sub> = low<br>CE <sub>1</sub> = high, V <sub>OUT</sub> = 5.5V, CE <sub>2</sub> = high,<br>CE <sub>3</sub> = low, CE <sub>4</sub> = low<br>V <sub>OUT</sub> = 0V |                  |     |             |                  |     | μA   |
| I <sub>O(OFF)</sub>                                   | Hi-Z state (82S181)                    |                                                                                                                                                                                                                                                                                                                                                                                                           |                  |     |             |                  |     |      |
|                                                       |                                        |                                                                                                                                                                                                                                                                                                                                                                                                           |                  |     |             |                  |     |      |
|                                                       |                                        |                                                                                                                                                                                                                                                                                                                                                                                                           |                  |     |             |                  |     |      |
| I <sub>OS</sub>                                       | Short circuit (82S181)                 |                                                                                                                                                                                                                                                                                                                                                                                                           |                  |     |             |                  |     | mA   |
|                                                       |                                        |                                                                                                                                                                                                                                                                                                                                                                                                           |                  |     |             |                  |     |      |
| I <sub>CC</sub>                                       | V <sub>CC</sub> supply current         |                                                                                                                                                                                                                                                                                                                                                                                                           | 140              | 175 |             | 140              | 185 | mA   |
| C <sub>IN</sub><br>C <sub>OUT</sub>                   | Capacitance<br>Input<br>Output         | V <sub>CC</sub> = 5.0V<br>V <sub>IN</sub> = 2.0V<br>V <sub>OUT</sub> = 2.0V                                                                                                                                                                                                                                                                                                                               |                  |     |             |                  |     | pF   |
|                                                       |                                        |                                                                                                                                                                                                                                                                                                                                                                                                           |                  |     |             |                  |     |      |

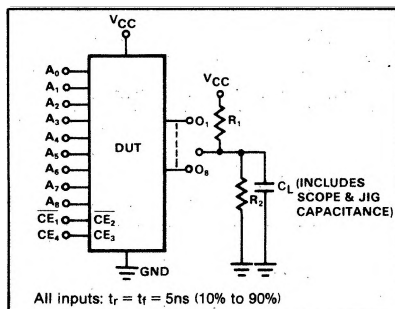
**AC ELECTRICAL CHARACTERISTICS** R<sub>1</sub> = 470Ω, R<sub>2</sub> = 1kΩ, C<sub>L</sub> = 30pF  
 N82S180/181:  $0^{\circ}\text{C} \leq T_A \leq +75^{\circ}\text{C}$ ,  $4.75\text{V} \leq V_{CC} \leq 5.25\text{V}$   
 S82S180/181:  $-55^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ ,  $4.5\text{V} \leq V_{CC} \leq 5.5\text{V}$ 

| PARAMETER                          | TO                     | FROM                   | N82S180/181 |                  |          | S82S180/181 |                  |          | UNIT |
|------------------------------------|------------------------|------------------------|-------------|------------------|----------|-------------|------------------|----------|------|
|                                    |                        |                        | Min         | Typ <sup>2</sup> | Max      | Min         | Typ <sup>2</sup> | Max      |      |
| T <sub>AA</sub><br>T <sub>CE</sub> | Access time<br>Output  | Address<br>Chip enable |             | 50<br>20         | 70<br>40 |             | 50<br>20         | 90<br>50 | ns   |
| T <sub>CD</sub>                    | Disable time<br>Output | Chip disable           |             | 20               | 40       |             | 20               | 50       | ns   |

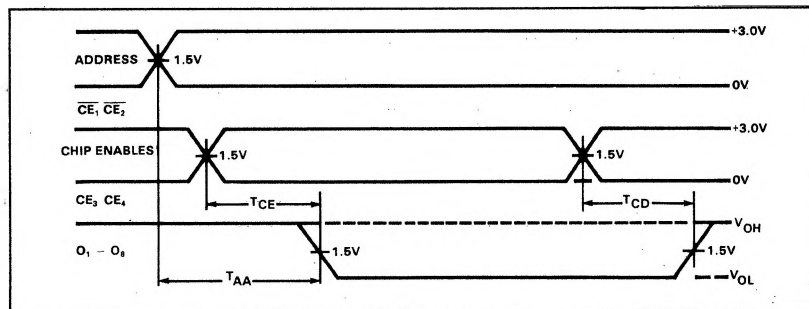
## NOTES

- Positive current is defined as into the terminal referenced.
- Typical values are at V<sub>CC</sub> = 5.0V, T<sub>A</sub> = +25°C.

## TEST LOAD CIRCUIT



## VOLTAGE WAVEFORM

PROGRAMMING SYSTEMS SPECIFICATIONS (Testing of these limits may cause programming of device.)  $T_A = +25^\circ\text{C}$ 

| PARAMETER                                                          | TEST CONDITIONS                                                | LIMITS |      |      | UNIT          |
|--------------------------------------------------------------------|----------------------------------------------------------------|--------|------|------|---------------|
|                                                                    |                                                                | Min    | Typ  | Max  |               |
| $V_{CCP}$ Power supply voltage<br>To program <sup>1</sup>          | $I_{CCP} = 375 \pm 75\text{mA}$ ,<br>Transient or steady state | 8.5    | 8.75 | 9.0  | V             |
| $V_{CCH}$ Verify limit<br>Upper                                    |                                                                | 5.3    | 5.5  | 5.7  | V             |
| $V_{CCL}$ Lower                                                    |                                                                | 4.3    | 4.5  | 4.7  | V             |
| $V_S$ Verify threshold <sup>2</sup>                                |                                                                | 1.4    | 1.5  | 1.6  | V             |
| $I_{CCP}$ Programming supply current                               | $V_{CCP} = +8.75 \pm .25\text{V}$                              | 300    |      | 450  | mA            |
| $V_{IH}$ Input voltage<br>High                                     |                                                                | 2.4    |      | 5.5  | V             |
| $V_{IL}$ Low                                                       |                                                                | 0      | 0.4  | 0.8  | V             |
| $I_{IH}$ Input current<br>High                                     | $V_{IH} = +5.5\text{V}$                                        |        |      | 50   | $\mu\text{A}$ |
| $I_{IL}$ Low                                                       | $V_{IL} = +0.4\text{V}$                                        |        |      | -500 |               |
| $V_{OUT}$ Output programming voltage <sup>3</sup>                  | $I_{OUT} = 200 \pm 20\text{mA}$ ,<br>Transient or steady state | 16.0   | 17.0 | 18.0 | V             |
| $I_{OUT}$ Output programming current                               | $V_{OUT} = +17 \pm 1\text{V}$                                  | 180    | 200  | 220  | mA            |
| $T_R$ Output pulse rise time                                       |                                                                | 10     |      | 50   | $\mu\text{s}$ |
| $t_p$ CE programming pulse width                                   |                                                                | 0.3    | 0.4  | 0.5  | ms            |
| $t_D$ Pulse sequence delay                                         |                                                                | 10     |      |      | $\mu\text{s}$ |
| $T_{PR}$ Programming time                                          | $V_{CC} = V_{CCP}$                                             |        |      | 12   | sec           |
| $T_{PSI}$ Initial programming pause                                | $V_{CC} = 0\text{V}$                                           | 6      |      |      | sec           |
| $\frac{T_{PR}}{T_{PR}+T_{PS}}$ Programming duty cycle <sup>4</sup> |                                                                |        |      | 50   | %             |
| $FL$ Fusing attempts per link                                      |                                                                |        |      | 2    | cycle         |

## NOTES

1. Bypass  $V_{CC}$  to GND with a  $0.01\mu\text{F}$  capacitor to reduce voltage spikes.
2.  $V_S$  is the sensing threshold of the PROM output voltage for a programmed bit. It normally constitutes the reference voltage applied to a comparator circuit to verify a successful fusing attempt.
3. Care should be taken to insure the  $17 \pm 1\text{V}$  output voltage is maintained during the entire fusing cycle.
4. Programming duty cycle is 50% after continuous programming at 100% duty cycle.
5. This is an updated method of programming and does not obsolete any programming systems presently being used.

**PROGRAMMING PROCEDURE**

1. Terminate all device outputs with a  $10k\Omega$  resistor to  $V_{CC}$ . Apply  $\overline{CE}_1$  = High,  $\overline{CE}_2$  = Low,  $\overline{CE}_3$  = High and  $\overline{CE}_4$  = High.
2. Select the Address to be programmed, and raise  $V_{CC}$  to  $V_{CCP} = 8.75 \pm .25V$ .
3. After  $10\mu s$  delay, apply  $V_{OUT} = +17 \pm 1V$  to the output to be programmed. Program one output at the time.
4. After  $10\mu s$  delay, pulse the  $\overline{CE}_1$  input to logic low for 0.3 to 0.5ms.
5. After  $10\mu s$  delay, remove  $+17V$  from the programmed output.
6. To verify programming, after  $10\mu s$  delay, lower  $V_{CC}$  to  $V_{CCH} = +5.5 \pm .2V$ , and apply a logic low level to the  $\overline{CE}_1$  input. The programmed output should remain in the high state. Again, lower  $V_{CC}$  to  $V_{CCL} =$
7.  $+4.5 \pm .2V$ , and verify that the programmed output remains in the high state.
8. Raise  $V_{CC}$  to  $V_{CCP} = 8.75 \pm .25V$ , and repeat steps 3 through 6 to program other bits at the same address.
9. After  $10\mu s$  delay, repeat steps 2 through 7 to program all other address locations.

**TYPICAL PROGRAMMING SEQUENCE**